

Amendments to the Claims

- 1 1. (Currently Amended) A method of ablation laser-machining, comprising the steps of:
2 generating pulses at a repetition rate of 0.1 to 50 MHz ~~by using~~ one or more
3 semiconductor-chip laser diodes, ~~each~~ a pulse-member of the pulses
4 having a pulse-duration of less than three picoseconds;
5 directing a ~~less than 1 square mm~~ beam of the pulses ~~to toward~~ a work-piece, the
6 beam having a spot area of less than one square millimeter at the surface
7 of the work-piece and with an ablating pulse-energy-density; and
8 scanning the beam ~~with~~ using a power-driven scanner to ablate a scanned area on
9 the work-piece at least 25 times larger than the ~~beam area~~ spot area of the
10 beam at the surface of the work-piece.

- 1 2. (Currently Amended) The method of claim 1, wherein the ablating pulse-energy-
2 density is 0.1 to 20 Joules per /square centimeter.

- 1 3. (Currently Amended) The method of claim 1, wherein the scanned area on the work-
2 piece is at least 100 times larger than the ~~beam area~~ spot area of the beam at the
3 surface of the work-piece.

- 1 4. (Original) The method of claim 1, wherein the pulse-duration is 50 femtoseconds to 1
2 picosecond.

- 1 5. (Currently Amended) The method of claim 1, wherein the beam area spot area of the
2 beam at the surface of the work-piece is 1 to 2,500 square microns.

1 6. (Currently Amended) The method of claim 1, wherein the ablating pulse-energy-
2 density is between 0.1 and 8 Joules/per square centimeter on the work-piece.

1 7. (Currently Amended) The method of claim 1, wherein the pulses are generated at 0.1
2 to 50 MHz.

1 8. (Original) The method of claim 1, wherein the beam is scanned in one direction.

1 9. (Original) The method of claim 1, wherein the beam is scanned in two directions.

1 10. (Original) The method of claim 1, wherein the beam is scanned in a spiral.

1 11. (Currently Amended) A method of ablation laser-machining, comprising the steps of:
2 generating 0.6 to 100 MHz pulses at a repetition rate of 0.6 to 100 MHz, a
3 duration of a member of the pulses being each pulse having a pulse-
4 duration less than three picoseconds;
5 directing a less than 1 square mm beam of the pulses toward a work-piece, the
6 beam having a spot area at the surface of a work-piece of less than 1
7 square millimeter to a work piece with an ablating pulse energy density;
8 and
9 scanning the beam with a power-driven scanner over a scanned area on the work-
10 piece at least 25 times larger than the spot area of the beam at the surface
11 of the work-piecebeam area.

1 12. (Currently Amended) The method of claim 11, wherein the ablation laser-machining
2 is part of a surgical procedure.

1 13. (Currently Amended) The method of claim 11, wherein the ablation laser machining
2 is part of a surgical procedure, and the ablating pulse-energy-density is between 1
3 and 10 times the an ablation threshold of the work-piece.

1 14. (Currently Amended) The method of claim 11, wherein the ablation laser machining
2 is part of a surgical procedure, and the ablating pulse-energy-density is between 1
3 and 3 times the an ablation threshold of the work-piece.

1 15. (Original) The method of claim 11, wherein the pulses are generated by at least one
2 optical amplifier.

1 16. (Currently Amended) The method of claim 11, wherein the pulses are generated by
2 one semiconductor optical amplifier (SOA) and the pulses contain have an energy
3 of less than about 50 micro-Joules per pulse.

1 17. (Currently Amended) The method of claim 11, wherein the pulses are generated by
2 one fiber amplifier and the pulses contain have an energy of less than 10 micro-
3 Joules per pulse.

1 18. (Original) The method of claim 11, wherein the beam is rasterized.

1 19. (New) A system comprising:

2 a semi-conductor chip laser diode configured for generating pulses at a repetition

3 rate between 0.1 and 50 MHz;

4 a semiconductor optical amplifier for amplifying the pulses, to generate amplified

5 pulses;

6 a dispersive element configured for compressing the amplified pulses; and

7 a scanning element configured for scanning a beam of the amplified pulses to

8 ablate a scanned area at least 25 times larger than spot area of the beam at

9 the surface of the work-piece.

1 20. (New) The system of claim 19 further comprising a cauterizing laser.